



Product Summary

Device	BV _{DSS}	R _{DS(ON)} Max	I _D T _A = +25°C
Q1	60V	13.5Ω @ V _{GS} = 10V	115mA
Q2	-50V	10Ω @ V _{GS} = -5V	-130mA

Description

This MOSFET has been designed to minimize the on-state resistance $(R_{DS(ON)})$ and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- General Purpose Interfacing Switch
- Power Management Functions
- Analog Switch

COMPLEMENTARY PAIR ENHANCEMENT MODE MOSFET

Features and Benefits

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Complementary Pair
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The BSS8402DWQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

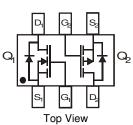
https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Case: SOT363
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Alloy 42 Leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208 3
- Terminal Connections: See Diagram
- Weight: 0.006 grams (Approximate)



Top View



Internal Schematic

Ordering Information (Note 4)

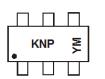
F	Part Number	Compliance Case		Packaging	
BS	SS8402DW-7-F	Standard	SOT363	3,000/Tape & Reel	
BS	S8402DW-13-F	Standard	SOT363	10,000/Tape & Reel	
BS	SS8402DWQ-7	Automotive	SOT363	3,000/Tape & Reel	
BS	S8402DWQ-13	Automotive	SOT363	10,000/Tape & Reel	
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.					

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See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and
<1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information



KNP = Product Type Marking Code $YM or <math>\overline{Y}M$ = Date Code Marking Y or \overline{Y} = Year (ex: G = 2019) M = Month (ex: 9 = September)

Date Code Key

Year	2003	2004	2005	2006	~	2018	2019	2020	2021	2022	2023	2024	2025	2026
Code	Р	R	S	Т	~	F	G	Н	Ι	J	К	L	М	Ν
Month	Jan	Feb	M	ar	Apr	May	Jun	Jul	Aug	Se	p (Oct	Nov	Dec
Code	1	2	3	3	4	5	6	7	8	9		0	Ν	D



Maximum Ratings – Total Device (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	200	mW
Thermal Resistance, Junction to Ambient	R _{0JA}	625	°C/W
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +150	°C

Maximum Ratings N-CHANNEL - Q1, 2N7002 Section (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		V _{DSS}	60	V
Drain-Gate Voltage $R_{GS} \le 1.0M\Omega$		V _{DGR}	60	V
Gate-Source Voltage	Continuous Pulsed	V _{GSS}	±20 ±40	V
Drain Current (Note 5)	Continuous Continuous @ +100°C Pulsed	ID	115 73 800	mA

Maximum Ratings P-CHANNEL – Q2, BSS84 Section (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		V _{DSS}	-50	V
Drain-Gate Voltage $R_{GS} \le 20K\Omega$		V _{DGR}	-50	V
Gate-Source Voltage	Continuous	V _{GSS}	±20	V
Drain Current (Note 5)	Continuous	I _D	-130	mA

Note: 5. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Incorporated's suggested pad layout document, which can be found on our website at http://www.diodes.com/package-outlines.html.



Electrical Characteristics N-CHANNEL – Q1, 2N7002 Section (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)					•		•
Drain-Source Breakdown Voltage		BV _{DSS}	60	70		V	$V_{GS} = 0V, I_D = 10\mu A$
Zero Gate Voltage Drain Current		I _{DSS}	_		1.0 500	μA	$V_{DS}=60V,V_{GS}=0V$
Gate-Body Leakage		I _{GSS}		_	±10	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 6)							
Gate Threshold Voltage		V _{GS(TH)}	1.0		2.5	V	$V_{DS}=V_{GS},\ I_{D}=250\mu A$
Static Drain-Source On-Resistance	@ T _J = +25°C	Р		3.2	7.5	Ω	$V_{GS} = 5.0V, I_D = 0.05A$
	@ T _J = +125°C	R _{DS(ON)}	_	4.4	13.5	12	$V_{GS} = 10V, I_D = 0.5A$
On-State Drain Current		I _{D(ON)}	0.5	1.0		Α	$V_{GS} = 10V, V_{DS} = 7.5V$
Forward Transconductance		g fs	80	_	_	mS	$V_{DS} = 10V, I_D = 0.2A$
DYNAMIC CHARACTERISTICS							
Input Capacitance		Ciss		22	50	pF	
Output Capacitance		Coss		11	25	pF	$V_{DS} = 25V, V_{GS} = 0V, f = 1.0MHz$
Reverse Transfer Capacitance		C _{rss}	_	2.0	5.0	pF	
SWITCHING CHARACTERISTICS		• 			•		•
Turn-On Delay Time		t _{D(ON)}	_	7.0	20	ns	$V_{DD} = 30V, I_D = 0.2A,$
Turn-Off Delay Time		t _{D(OFF)}		11	20	ns	$R_L = 150\Omega, V_{GEN} = 10V, R_{GEN} = 25\Omega$

Electrical Characteristics P-CHANNEL – Q2, BSS84 Section (@TA = +25°C, unless otherwise specified.)

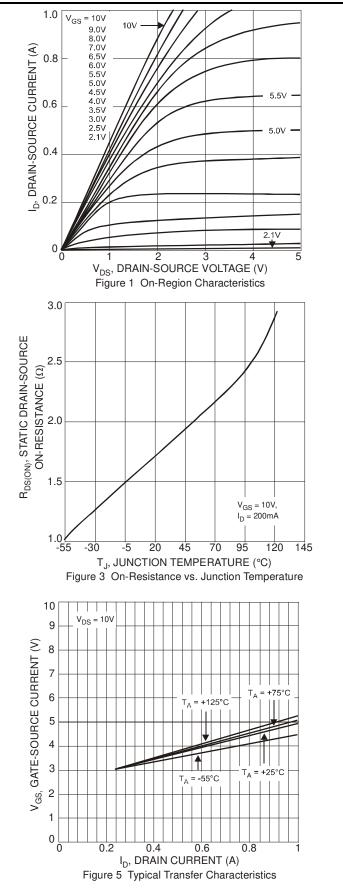
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)						
Drain-Source Breakdown Voltage	BV _{DSS}	-50			V	$V_{GS} = 0V, I_D = -250\mu A$
Zero Gate Voltage Drain Current	I _{DSS}			-1 -2 -100	μA	$ \begin{array}{l} V_{DS} = -50V, V_{GS} = 0V, T_J = +25^\circ C \\ V_{DS} = -50V, V_{GS} = 0V, T_J = +125^\circ C \\ V_{DS} = -25V, V_{GS} = 0V, T_J = +25^\circ C \end{array} $
Gate-Body Leakage	Igss	_	_	±10	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 6)						
Gate Threshold Voltage	V _{GS(TH)}	-0.8	_	-2.0	V	$V_{DS} = V_{GS}, I_D = -1mA$
Static Drain-Source On-Resistance	R _{DS(ON)}	_	_	10	Ω	$V_{GS} = -5V, I_D = -0.100A$
Forward Transconductance	g fs	0.05	_	_	S	$V_{DS} = -25V, I_D = -0.1A$
DYNAMIC CHARACTERISTICS						
Input Capacitance	C _{iss}	_	_	45	pF	
Output Capacitance	C _{oss}	_	_	25	pF	V _{DS} = -25V, V _{GS} = 0V, f = 1.0MHz
Reverse Transfer Capacitance	C _{rss}	_		12	pF	
SWITCHING CHARACTERISTICS				•		
Turn-On Delay Time	t _{D(ON)}	_	10	_	ns	V _{DD} = -30V, I _D = -0.27A,
Turn-Off Delay Time	t _{D(OFF)}	_	18			$R_{GEN} = 50\Omega$, $V_{GS} = -10V$

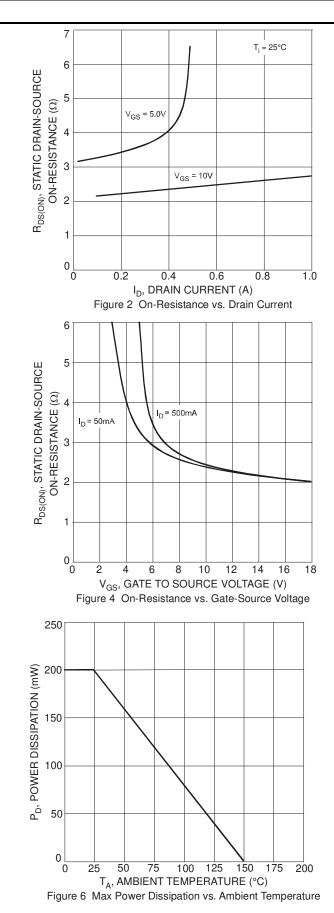
Note: 6. Short duration pulse test used to minimize self-heating effect.



BSS8402DW

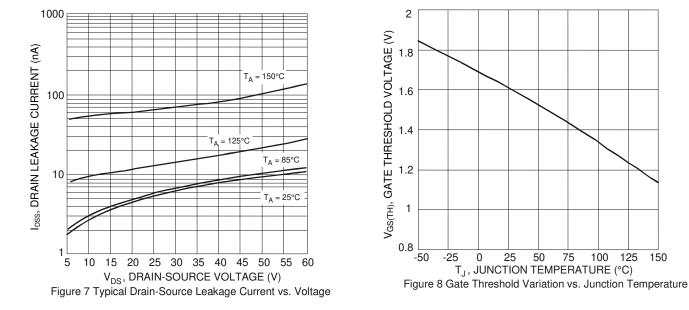
N-CHANNEL – 2N7002 Section



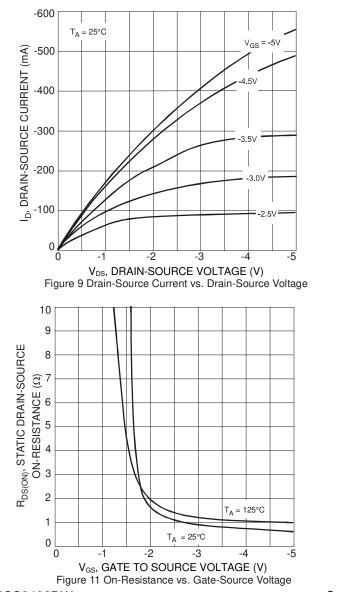


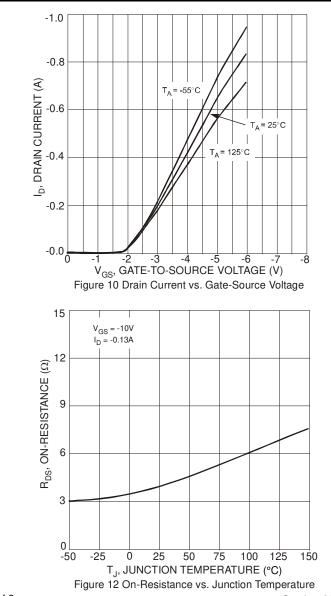


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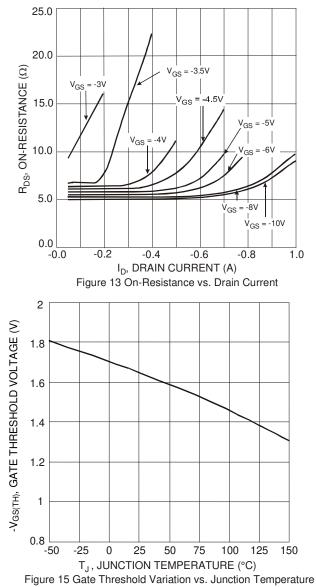


P-CHANNEL – BSS84 Section









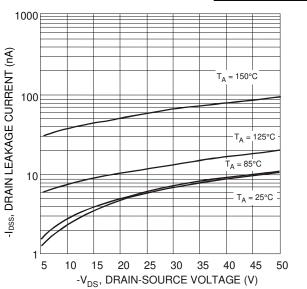


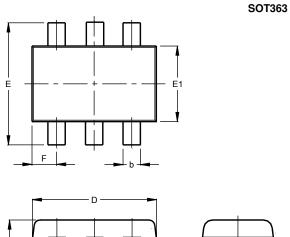
Figure 14 Typical Drain-Source Leakage Current vs. Voltage

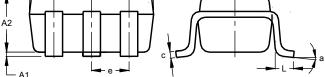
BSS8402DW



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

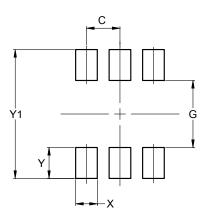




	SO	T363					
Dim	Min	Max	Тур				
A1	0.00	0.10	0.05				
A2	0.90	1.00	0.95				
b	0.10	0.30	0.25				
С	0.10	0.22	0.11				
D	1.80	2.20	2.15				
E	2.00	2.20	2.10				
E1	1.15	1.35	1.30				
е	C).650 E	SC				
F	0.40	0.45	0.425				
L	0.25	0.40	0.30				
а	0°	8°					
All I	All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions C G

Х

Υ

Y1

Value

(in mm)

0.650

1.300

0.420

0.600

2.500

BSS8402DW
Document number: DS30380 Rev. 23 - 2

SOT363



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